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1	Molecular Engineering Using an Anthanthrone Dye for Low
2	Cost Hole Transport Materials: A Strategy for Dopant Free,
3	High Efficiency and Stable Perovskite Solar Cells
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24 Abstract

25 In this report, we are presenting highly efficient and humidity-resistant perovskite solar cells (PSCs) using two new small molecule hole transporting materials (HTM) made from a cost-26 effective precursor anthanthrone (ANT) dye, namely ACE-ANT-ACE and TPA-ANT-TPA. 27 We have systematically compared our newly developed HTMs with the conventional 28 29 2,2',7,7'-tetrakis(N,N'-di-p-methoxyphenylamino)-9,9'-spirbiuorene (Spiro-OMeTAD). ACE-ANT-ACE and TPA-ANT-TPA were used as a dopant free HTMs in mesoscopic 30 31 TiO₂/CH₃NH₃PbI₃/HTM solid-state PSCs, and the performance as well as stability were compared with Spiro-OMeTAD based PSCs. After extensive optimization of the metal oxide 32 33 scaffold and device processing conditions, dopant-free novel TPA-ANT-TPA HTM based 34 PSCs devices achieved a maximum PCE of 17.5% with negligible hysteresis. An impressive current of 21 mA/cm² obtained is also confirmed from photocurrent density with a higher fill 35 factor of 0.79. The obtained PCE of 17.5% utilizing TPA-ANT-TPA is higher performance 36 37 than the devices prepared using doped Spiro-OMeTAD (16.8%) as hole transport layer at 1 sun condition. It is found that doping of LiTFSI salt increases hygroscopic characteristics in 38 Spiro-OMeTAD this leads to the fast degradation of solar cells. While, solar cells prepared 39 using undoped TPA-ANT-TPA shows dewetting and improved stability. Additionally, the 40 new HTMs form a fully homogeneous and completely covering thin film on the surface of 41 the active light absorbing perovskite layers that acts as a protective coating for underlying 42 perovskite films. This breakthrough paves the way for development of new inexpensive, 43 more stable, and highly efficient ANT core based lower cost HTMs for cost effective 44 45 conventional and printable PSCs.

46

49 Photovoltaic or solar cells are currently considered as the possible and suitable alternative for traditional non-conventional energy harvesting technology to tackle the issues of 50 51 environmental pollution, climate change and potential future shortage of hydrocarbon-based 52 energy supply. With the goal of making this alternative feasible, much research on various 53 solar cell technologies has been performed. The main challenges include reducing the cost, 54 increasing the power conversion efficiency (PCE) values, and improving stability to enable large-scale commercial manufacturing for public use. Apart from conventional high 55 performance and stable silicon based inorganic solar cells,^[1] dye sensitised solar cells 56 (DSSC),^[2] organic solar cells (OSCs)^[3] and perovskite solar cells(PSCs)^[4, 5] are some 57 58 emerging technologies where the active light absorbing layer can be deposited on large scale 59 using either pure organic or organic-inorganic solution processable light absorbing 60 semiconducting layer. These technologies are becoming attractive options due to the potential 61 for lower cost, optoelectronic tunability (energy levels and optical band gap), high efficiency 62 and opportunities to scale them up in the form of flexible prototypes using roll to roll printing.^[4, 6] Among various organic based light absorbing semiconductors, metal-free 63 64 organic dyes are prospective candidates on account of their practical advantages, including high molar absorption coefficients, facile structure tuning, easy charge carrier mobility 65 modulation, and simple and inexpensive syntheses.^[7] The dye-based semiconductors have 66 67 been employed successfully in various solar cell devices either as donors (p-type materials) 68 or acceptors (n-type materials). Among various and numerous types of dyes, recently, some 69 of the key dyes such as the dark red diketopyrrolopyrrole (DPP) and isoindigo (IS) have been 70 widely used as a significant building blocks for designing and synthesizing high performance low band gap materials for organic and dye sensitized solar cells.^[8] In addition to OSCs and 71 DSSCs, recently, carbazole-based low cost dyes have been successfully used as hole-72 transporting materials (HTMs) in PSCs and an impressive PCE has been achieved.^[9] 73

74 Recently, dibenzo[def,mno]chrysene (anthanthrene), one type of polycyclic aromatic hydrocarbons, has been used intensively as a versatile building block for designing advanced 75 functional materials for organic field-effect transistors (OFETs), organic light emitting diodes 76 (OLED) and organic solar cells (OSCs) devices, due to its outstanding properties.^[10, 11, 12] The 77 78 commercially available anthanthrene dye is not only cost-effective but also possesses a good 79 environmental stability and provides good solubility. Among anthanthrene derivatives, 4,10-80 dibromoanthanthrone, named as VAT Orange 3 (Scheme 1), is a useful scaffold due to its 81 various exciting features. Firstly, the conjugation backbone of the dye can be extended and its 82 optoelectronic properties can be tuned easily via functionalization of any chemical moiety 83 (either aliphatic or aromatic depending on requirements) at the possible 4, 10 and 6, 12 axes.^[13-15] Secondly, the solution processibility aspect can be enhanced by introducing either 84 longer straight or branched alkyl chains via the bromine atoms at the 4 and 10 positions or at 85 the 6 and 12 positions via alkylation.^[13] Thirdly, the possibilities of tuning the starting n-type 86 87 material (due to two ketonic groups at 6 and 12) to p-type organic semiconductors by introducing electron donating groups.^[14] In addition to the above features, the central fused 88 89 aromatic six-membered rings in the centre deliver structural planarity leading to ordered morphology in thin films which is essential for better charge delocalization and transport.^[12] 90 91 Furthermore, this compound seems to be crystallized simply due to its symmetrical structure 92 and can provide ample opportunities to vary the UV-visible absorption range based on rigid and extended π -conjugated backbone.^[16] Although a handful of anthanthrone derivatives 93 94 were used successfully in OFETs, OLED and OSCs, till date there are no reports using this 95 cost-efficient dye and its derivatives as a hole transporting material in the fast moving PSCs 96 technology.

97 In recent years, PSCs have gained enormous attention from both academia and industry98 due to their easy processibility, potentially lower cost and ability to reach the performance

99 close to the solar cell technologies currently used globally. The rapid development of this 100 technology is almost comparable to common and traditional solar energy technologies, such 101 as copper indium gallium selenide (CIGS), cadmium telluride (CdTe) and silicon. From the first initial PCE of 3.8% reported in 2009,^[17] the power conversion efficiency (PCE) of PSCs 102 has now reached 22.1%.^[18] One of key points resulting in the rapid success is the presence of 103 104 a hole-transporting layer (HTL) in the devices. This layer not only assists to transport the 105 holes after exciton dissociation but also plays a significant role in controlling the stability, 106 supressing charge recombination and preventing the perovskite layer from the invasion of the moisture/oxygen and electrode penetration.^[19, 20] Earlier works showed that while the PCE of 107 perovskite devices with a HTL has recorded greater than 20%,^[21-23] the efficiency in the 108 absence of this layer has been around 14%.^[24] In terms of designing materials for the HTL, 109 various inorganic,^[25] small molecular,^[26, 27] and polymeric^[28] HTMs have been developed. 110 111 Among them, small molecules are more attractive and can offer considerable benefits such as 112 simplicity of purification, high purity, definite molecular weight, promising tunable highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) 113 energy levels and good batch-to-batch reproducibility.^[29] Also, small molecular HTMs have 114 been proven to be one of the best choices of materials till date compared to other type of 115 116 HTMs. The 2, 2', 7, 7'-tetrakis-(N,N-di-p-methoxyphenylamine)-9,9'-spiro-bifluorene (Spiro-OMeTAD) has been recognized as one of the key candidates which has achieved the 117 highest PCE close to 20.8% in PSCs.^[21] However, the major drawback of Spiro-OMeTAD is 118 119 that it gives such a high performance only in combination with some dopants, which are often vulnerable to moisture, and this critically determines the stability of solar cell devices.^[26, 30] 120 In addition, tedious synthesis and a cost too high for commercial use have impeded overall 121 PSC development.^[22, 26] 122

In order to replace Spiro-OMeTAD, researchers worldwide have been designing and developing alternative HTMs. Among them, the triphenylamine (TPA) based HTMs in combination with various different π -functional moieties have shown remarkable success due to simplicity in synthesis and promising PCE value upward growth.^[31, 32-35] Thus, our group has designed HTMs by using anthanthrone dye as a starting cut-rate central core decorated with TPA end-capping groups at 4 and 6-positions. This is the first report of using this dye in PSC devices.

Herein, we have designed and synthesized two innovative and cost effective HTMs,
namely, 4,4'-(6,12-bis(octyloxy)-6,12-dihydronaphtho[7,8,1,2,3-*nopqr*]tetraphene-4,10diyl)bis(*N*,*N*-bis(4-methoxyphenyl)aniline) (TPA-ANT-TPA) and 4,10-bis(1,2dihydroacenaphthylen-5-yl)-6,12-bis(octyloxy)-6,12-dihydronaphtho[7,8,1,2,3-

134 *nopqr*]tetraphene (ACE-ANT-ACE) using low cost anthanthrone core as starting material (as 135 shown in Scheme 1). Apart from the novelty of using the anthanthrone dye as a precursor, we 136 have used for the first time 1,2-dihydroacenaphthylene (ACE) functional group as an end 137 capping group as well as TPA. TPA-ANT-TPA and ACE-ANT-ACE have been successfully 138 used as HTL in conventional n-i-p perovskite devices. The device structure includes 139 glass/FTO/compact-TiO₂/Mesoporous-TiO₂/CH₃NH₃PbI₃/HTL/Ag. First, fluorine doped tin 140 oxide (FTO) commercially available substrates were used as a transparent conducting anode 141 followed by deposition of titanium dioxide (TiO₂) electron transporting compact layer, active perovskite layer and TPA-ANT-TPA & ACE-ANT-ACE based new HTL thin films, 142 143 respectively. Lastly, silver (Ag) as a cathode electrode was deposited to complete the device 144 fabrication. Further fabrication procedure details can be found in the Supporting Information (ESI[†]). Under standard illumination (AM 1.5G and 100 mW cm⁻²), the average PCE of 145 146 devices using ACE-ANT-ACE and TPA-ANT-TPA HTMs have achieved 11.4% and 16%, respectively. Interestingly, these PCE values are without any additives and they are 147

148 comparable to that of doped Spiro-OMeTAD (16.8%) devices under similar working 149 condition. Additionally, after first 20 h in the ambient environment (room temperature, 58% 150 humidity), while the PCE of unsealed Spiro-OMeTAD based devices retained 2% of its initial 151 value, that of TPA-ANT-TPA still retained 80% of its original performance which is one of 152 the most important striking features of our newly developed HTM. After extensive 153 optimization of the metal oxide scaffold and device processing conditions, novel TPA-ANT-TPA HTM based PSCs devices achieved a maximum PCE of 17.5%. The overwhelming 154 155 advantages such as high performance and higher stability make our newly developed HTMs 156 promising candidates for low cost perovskite solar cell devices.

157 Novel anthanthrone core derivatives end capped with methoxy triphenylamine at both 158 ends (TPA-ANT-TPA and ACE-ANT-ACE have been designed (Figure 1) and synthesized 159 by classical Suzuki coupling. The synthesis is quite straightforward and various steps 160 involved are shown in Scheme 1. Initially, the reaction of 4-bromoaniline (1) with 1-iodo-4-161 methoxybenzene, strong base KOH, CuCl, and 1,10-phenanthroline monohydrate in toluene 162 produced the intermediate 4-bromo-N,N-bis(4-methoxyphenyl)aniline (2). Afterwards, in 163 presence of bis(pinacolato)diboron, strong base potassium acetate. 1. 1'-164 bis(diphenylphosphino)ferrocene]dichloropalladium(II) catalyst in dimethyl formamide solution, the compound 2 was converted to 4-methoxy-N-(4-methoxyphenyl)-N-(4-(4,4,5,5-165 166 tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (3) at 120 °C overnight. Meanwhile, the 167 alkylation of 4,10-dibromoanthanthrone (4) at 2 and 6 positions aimed to enhance the 168 solubility and make dibromoanthanthrone become the electron rich unit. The alkylation was 169 operated under base environment of aqueous sodium hydroxide and Aliquat 336, catalyst of sodium dithionite and 1-bromooctane at 80 °C overnight. Then 4,10-dibromo-6,12-170 171 bis(octyloxy)anthanthrene (5) was collected with high yield. The final HTMs TPA-ANT-172 TPA and ACE-ANT-ACE were produced based on the Suzuki coupling reaction (2M

173 potassium carbonate as a base, tetrakis (triphenylphosphine) palladium (0) as catalyst in toluene solvent). ACE-ANT-ACE was synthesized from compound 5 and 2-(1,2-174 175 dihydroacenaphthylen-5-yl)-4,4,5,5-tetramethyl-1,3,2-dioxaborolane, whereas TPA-ANT-176 TPA was made from compound 5 and compound 3. All reactions were stirred at 120 °C for 48 h. After purification, TPA-ANT-TPA and ACE-ANT-ACE's yield was to be of 60% and 177 178 65%. Their purity was proved by proton and C13 nuclear magnetic resonance (NMR) spectroscopy (Figure S1-S5, ESI[†]). The solubility of these anthanthrone derivatives was 179 180 extremely good in most common organic solvents such as chloroform, dichloromethane, and 181 chlorobenzene.

182 To understand the structures and electronic properties of these molecules, density 183 functional theory (DFT) calculations at the B3LYPr level of theory using the basis set 6-31g(d, p) were performed. A PCM model of the chloroform solvent was used.^[36] The results 184 185 are shown in Figure 1 and summarized in Table S1 (ESI⁺). The electron density of the LUMO is primarily distributed over the π -conjugated system through the anthanthrone 186 187 (ANT) core in both molecules. The HOMO of ACE-ANT-ACE has the electron density 188 localized mainly on the ANT unit, whereas for TPA-ANT-TPA, electron density delocalized 189 over the entire molecule including the electron-rich TPA unit as expected. The lack of 190 HOMO density on the ACE moiety is not unusual, as bonded fused aromatic units tend to 191 preserve their HOMO-like orbitals which become HOMO-n in the bonded system. 192 HOMO/LUMO energy levels for ACE-ANT-ACE are -4.80/-2.06 eV whereas for TPA-ANT-193 TPA, is they are -4.67/-2.04 eV respectively. Consequently, the band gap of ACE-ANT-ACE 194 and TPA-ANT-TPA is calculated to be 2.74 and 2.63 eV, respectively. Optical absorption 195 maxima were at 474 nm for ACE-ANT-ACE (HOMO-JLUMO dominated) and at 482 nm 196 for TPA-ANT-TPA (dominated by two transitions, HOMO→LUMO at 524 nm and HOMO-197 2→LUMO at 467 nm), giving optical band gaps of 2.61 and 2.58 eV respectively which are

in a good agreement with the experimentally estimated optical gaps of 2.56 and 2.48 eV(Table 1).

200 The normalized UV-vis absorption (Figure 2a) and emission (Figure S6, ESI⁺) spectra 201 of ACE-ANT-ACE and TPA-ANT-TPA in chloroform (CF) solutions and thin films were 202 measured and the relevant data was listed in Table 1. The pattern of the spectra in the thin 203 films is the same as those of the solutions, which implies that no significant crystallization in thin films.^[37] The optical absorption of both materials exhibits strong peaks in the ultraviolet 204 205 (300 - 350 nm) region and lower ones in the visible (400 - 500 nm) region, which has been noticed in the past attempt regarding small molecular ANT derivatives.^[10] Compound ACE-206 207 ANT-ACE exhibits the absorption maxima at 461 nm for solution and 467 nm for thin film 208 respectively. The thin film absorbance data of ACE-ANT-ACE is blue-shifted in UV region 209 and slightly red shifted in visible area compared to the solution data. Compound TPA-ANT-210 TPA unveils absorption maxima at 465 nm for solution and 473 nm for thin film respectively. 211 The absorption spectra of solid-state films illustrate slightly red-shifted and little broadened absorption than those measured in the solution, as is expected due to intermolecular 212 213 interactions in the solid state. Moreover, the optical absorption spectrum of TPA-ANT-TPA 214 is slightly red-shifted in comparison to ACE-ANT-ACE, which could be ascribed to the higher conjugation and higher electron-donating ability of TPA moiety compared to the 1,2-215 216 dihydroacenaphthylene (ACE) moiety. The optical band gap of ACE-ANT-ACE and TPA-217 ANT-TPA are found to be 2.56 and 2.48 eV, respectively, which was estimated from the 218 onset of solid-state absorption.

As shown in Figure S6 (ESI[†]), the emission maximum of ACE-ANT-ACE and TPA-ANT-TPA are depicted at 480 and 553 nm, respectively. Stokes shifts were estimated from the gap between the maximum of absorption and emission spectra. These materials possessed a large Stokes shift of 157 and 228 nm compared to that of Spiro-OMeTAD (44 nm)^[38]. A large Stoke shift implies the different and large geometrical changes between the ground- and
excited-state geometry and is a reflection of molecular flexibility. This property also
enhances the pore filling of a hole transport ability of materials.^[38-40]

The thermogravimetric analysis (TGA) was operated under a nitrogen atmosphere in 226 227 order to investigate the thermal stability of new molecules, which lost less than 5% weight 228 upon heating. The TGA curves were shown in Figure S7 (ESI[†]) and recorded in Table 1. The decomposition of ACE-ANT-ACE and TPA-ANT-TPA started at temperatures 265 °C and 229 230 280 °C, respectively, which shows that the small molecules are thermally stable HTMs for 231 PSCs devices. Upon evaluating these materials in DSC measurement (Figure S8, ESI⁺), the 232 glass transition temperature (T_g) was not observed but the melting points were measured at 215 °C for ACE-ANT-ACE and 265 °C for TPA-ANT-TPA, respectively. The observed 233 melting temperatures of both compounds are comparable to that of Spiro-OMeTAD (248 234 ^oC).^[40] 235

236 The experimental estimation of the HOMO and LUMO energy levels of ACE-ANT-237 ACE and TPA-ANT-TPA were performed using photoelectron spectroscopy in air (PESA) 238 (Figure 2b) and cyclic voltammetry (CV) (Figure S9, ESI⁺) techniques. The HOMO and 239 LUMO energy level values are presented in the Table 1. In comparison to the HOMO value 240 of active perovskite layer (-5.46 eV), the HOMO value of ACE-ANT-ACE (-5.32 eV) is 241 greater, whereas for TPA-ANT-TPA, the HOMO value (-5.41 eV) is higher than but very 242 close to the perovskite HOMO value. The HOMO values obtained by CV data are also in a 243 good agreement with PESA data. Since the PESA measurements were done in the thin film form they are more relevant to actual devices. As per an earlier report, the hole transport 244 245 ability can be impended by an excessively small band offset of the HOMO between perovskite and hole injection layers, whereas a very large band offset could cause the 246 reduction of the open-circuit voltage (V_{oc}).^[41] Meanwhile, all LUMO values of HTMs are 247

greater than that of the perovskite layer (-3.93 eV) proving that the new HTMs can block
electron transfer to HTL.

250 After characterizing both new small molecules optically, thermally and 251 electrochemically, the conventional perovskite devices were fabricated with the aim of to study the effect of the hole transport layers on the device performance. PSC devices with the 252 253 (FTO/compact-TiO₂/Mesoporous-TiO₂/CH₃NH₃PbI₃/HTL/Ag), same architecture and different HTM layers were prepared as previously described.^[42] The configuration of 254 255 mesoscopic heterojunction perovskite solar cells was characterized by the cross-sectional 256 scanning electron microscopy (SEM) and shown in Figure 2d. A dense compact-TiO₂ 257 blocking layer (~30 to 40 nm) is first deposited on the FTO substrate by spray pyrolysis, 258 while a mesoporous n-type mp-TiO₂ layer is formed by spin-coating of diluted TiO₂ paste. 259 The CH₃NH₃PbI₃ absorber layer was then applied on mesoporous TiO₂ by solvent engineering reported by Seok's group.^[43] The perovskite solution was prepared by dissolving 260 261 50 wt% of CH₃NH₃PbI₃ in the mixed dimethyl sulfoxide (DMSO) and γ - butyrolactone 262 (GBL) DMSO/GBL. Around 120 nm thick HTLs were applied to the top CH₃NH₃PbI₃ layer 263 by spin coating. Finally, silver as a counter electrode was deposited by thermal evaporation. 264 The thickness of mesoporous TiO_2 and perovskite is ~550 nm, whereas the capping layer of perovskite is estimated to be ~100 nm. Bigger crystals of TiO_2 in the capping layer assist in 265 266 saturated light absorption and enhancing the external quantum efficiency (EQE) in the red-267 light range.

For a valid comparison of performance in terms of PCE and stability, we prepared new dopant-free HTMs based devices and standard devices with dopant using conventional Spiro-OMeTAD (with additional additives, including *t*BP and LiTFSI) as the HTM. The optimized champion device efficiency for three different HTMs and corresponding photovoltaic performance parameters are shown in **Figure 3**a, b and **Table 2**. The TPA-ANT-TPA HTM

based PSC device (Figure 3a) shows the highest champion device efficiency of 17.5% (J_{sc} = 273 21.07 mA cm⁻², $V_{oc} = 1.03$ V and FF = 79.6) whereas a bit lower PCE of 13.1% is recorded 274 with $J_{sc} = 18.7 \text{ mA cm}^{-2}$, $V_{oc} = 1.03 \text{ V}$ and FF = 67 in case of ACE-ANT-ACE (Figure 3a). 275 276 Meanwhile, doped Spiro-OMeTAD-based device performance (Figure 3b) approaches the PCE of 16.8% with J_{sc} of 21.09 mA cm⁻², $V_{oc} = 1.04$ V and FF = 76.8. In addition, there is a 277 no hysteresis on the reverse scan (0 V to V_{oc}) at low scan speed of 0.1 V/s for TPA-ANT-278 279 TPA and Spiro-OMeTAD based devices. However, for ACE-ANT-ACE HTM based devices, 280 a negligible hysteresis resulted in a lowered PCE from 13.1% to 11%. As per previous 281 discussion, an excessively small band offset of the HOMO between perovskite and HTL may hamper the effective hole transport ability.^[41] However, our study significantly showed that 282 283 even though the work function of TPA-ANT-TPA is very close to that of perovskite active layer, still the better PCE than that of ACE-ANT-ACE could be achieved. The lower V_{oc} of 284 285 ACE-ANT-ACE is due to the large band offset and HOMO value difference between this compound and active layer perovskite.^[41] Furthermore, TPA-ANT-TPA based PSCs shows 286 improvement in short circuit current ($J_{sc} = 21.07 \text{ mA cm}^{-2}$) compared to ACE-ANT-ACE (J_{sc}) 287 =18.7 mA cm⁻²) which is due to the shallower HOMO of TPA-ANT-TPA that allows an 288 effective hole extraction. 289

To the best of our knowledge, the obtained PCE of 17.5% using TPA-ANT-TPA HTM is very high compared to other HTMs reported in the literature taking dopant-free aspect into account.^[19, 26, 44, 45] The hysteresis behaviours of champion devices and statistics of a total of 90 devices prepared using three different hole transporting layers is shown in Figure S13, Table 2 and S11 respectively (ESI[†]). The statistics of total 90 PSCs prepared using TPA-ANT-TPA, ACE-ANT-ACE and Spiro-OMeTAD exhibits an average device efficiency of 16%, 11.4% and 13.8% respectively. As shown in Figure 3c, the devices with TPA-ANT- TPA exhibit EQE values above 78 to 82% from 365 nm to 650 nm covering the entire UV
region with the highest EQE of 82% observed at 470 nm.

299 To measure the hole transport properties, a space charge limited current (SCLC) method was used. A spin-coated layer of the HTMs on an ITO/PEDOT-PSS substrate, 300 301 followed by an evaporated gold counter electrode was prepared for measurements. As the 302 ITO and gold work functions are close to the HTM's HOMO level, this creates a hole-only 303 device from which the mobility can be determined. The highest hole mobility (Table 2, Figure S14 (ESI^{\ddagger})) of 2.6 x 10⁻⁴ cm² V⁻¹ s⁻¹ was obtained with TPA-ANT-TPA and was 304 higher than that with Spiro-OMeTAD (1.5 x 10^{-4} cm² V⁻¹ s⁻¹) and ACE-ANT-ACE (2.4 x 10^{-5} 305 $cm^2 V^{-1} s^{-1}$). This is consistent with the good fill factor and efficiency performance shown by 306 307 perovskite devices prepared utilizing TPA-ANT-TPA as HTL.

308 The stability of PSC devices is one of the most critical parameter and most discussed 309 parameter in perovskite solar cell community. Perovskite solar cell stability is also one of the 310 major hurdles to commercialize this technology for the industrial scale. Ambient humidity is 311 one of the most important factors responsible for the quick degradation of PSCs and this is due to the salt type nature of CH₃NH₃PbI₃ active layer in PSC.^[46-48] We studied the stability 312 313 of fabricated champion devices without any encapsulation at high humidity conditions (relative humidity (RH) \geq 58%, temperature = 22°C, in dark condition) for our newly 314 315 developed ACE-ANT-ACE, TPA-ANT-TPA and standard classical Spiro-OMeTAD HTMs 316 (as shown in Figure 4). A simple stability setup used is shown in Figure S12c, d (ESI[†]) and photovoltaic performance was measured at 1000 wm⁻² (AM1.5G) using regular aging 317 318 intervals. In particular, photovoltaic properties of our novel TPA-ANT-TPA and Spiro-319 OMeTAD in the aging test are detailed in Figure 4a, b. Additionally, the efficiency of all 320 HTMs based devices are evaluated under identical conditions and depicted in Figure 4. The 321 degradation test results show that the Spiro-OMeTAD HTM based devices degraded at a faster rate compared to **TPA-ANT-TPA** and **ACE-ANT-ACE** HTM based devices. Additionally, we have tested the champion devices using all three HTLs under continuous 1 sun illumination in ambient air for 200 hours exposure (Figure S15, (ESI†)) and found the TPA-ANT-TPA and ACE-ANT-ACE HTM based devices shows a smaller drop in efficiency, and still sustain improved stability over Spiro-OMeTAD based devices.

327 Moreover, the novel ANT core along with extended TPA groups offers a better surface coverage and in addition the absence of the Li salt also gives better stability^[4, 49] for TPA-328 329 ANT-TPA and ACE-ANT-ACE HTM based PSCs than that of Spiro-OMeTAD HTL based 330 PSCs. It can be seen that the PCE values diminished rapidly down to $\sim 2\%$ (after only 10 331 hours) for Spiro-OMeTAD based devices. However, the devices based on TPA-ANT-TPA 332 are seen to be more stable with observed efficiency reduced to ~14% (after >50 hours exposure to 58% RH conditions) and 15% (after 200 hours of continuous illumination to 1 333 334 sun in ambient air).

The overall superior performance of PCE and stability of TPA-ANT-TPA over Spiro-OMeTAD provide a promising alternative replacement for high performance perovskite solar cells. The reason for the dramatic improvement in stability of TPA-ANT-TPA based PSCs (compare to Spiro-OMeTAD and ACE-ANT-ACE) and improvement in efficiency from 13% with ACE-ANT-ACE to 17.5% with TPA-ANT-TPA are further investigated by steady state photoluminescence (**Figure 5**a) and morphological measurements (**Figure 6**).

The measurement of steady state photoluminescence based on a simple architecture: Glass/CH₃NH₃PbI₃/HTM is shown in Figure 5a. In order to eliminate any quenching effect related to electron transfer to the oxide layer, we avoided to use of a TiO₂ layer while doing PL measurements. During these PL measurements, we have to make sure that the photoluminescence quenching is only caused by the hole transport layer and is not due to any other materials. All the HTL thin films were excited at 550 nm wavelength. From the data, it 347 is quite clear that the bare perovskite film without any HTM (black curve) exhibits a high PL emission intensity as a result of the formation of good quality (crystallinity and homogeneous 348 349 surface) perovskite film. Such observations are similar to our earlier studies and they are also comparable with reported data.^[42, 50] Upon deposition of HTM on the perovskite layer, a 350 351 significant reduction in PL emission was observed. Perovskite films covered with TPA-ANT-352 TPA (blue curve) and ACE-ANT-ACE (green curve) HTL's display a stronger PL quenching 353 (~95 to 80%) than the films covered with Spiro-OMeTAD (~60 to 65%) HTL. These results 354 clearly indicate a higher PL quenching ability of our newly developed TPA-ANT-TPA and 355 ACE-ANT-ACE materials compared to Spiro-OMeTAD. Between the two materials, TPA-356 ANT-TPA exhibits more efficient exciton dissociation efficiency and ensures a more efficient 357 charge generation and high hole mobility as well as low recombination at the TPA-ANT-358 TPA/CH₃NH₃PbI₃ interface.

359 The time resolved photoluminescence measurement was performed and shown in 360 Figure 5b to verify the improved hole transport properties. Bare perovskite films deposited on 361 glass substrate as well as with different hole transport layers show biphasic kinetics. The fast 362 component decays in picosecond (due to 80 ps laser pulse) and the slower component has a 363 time constant of 10-15 ns. The fast component represents trap filling. As the hole transfer 364 films are deposited on bare glass - perovskite layer for direct probing, this gives us a good 365 estimation about quenching of the photoluminescence due to hole transport layers. As shown in our previous work, a good quality glass-perovskite sample shows a lifetime of 8-10 ns.^[50] 366 367 In this case, similarly we have obtained 8 ns lifetime for the bare perovskite sample (without 368 the hole transporting layer). This, along with the high intensity PL, further confirms the 369 quality of the perovskite film. Bare perovskite films show an average life time of 200 ns. 370 After the introduction of TPA-ANT-TPA hole transporting layer above the perovskite layer 371 the average decay time (T) shortened to ~20.2 ns. The fast decay lifetime (T₁) of all 3 hole

transporting materials decreased from 33 ns (bare perovskite without HTL) to 20 ns for ACE-ANT-ACE, to 12 ns for Spiro-OMeTAD and 6 ns for TPA-ANT-TPA hole transporting layer. At the same time the weight fraction increased from 3% (bare perovskite film) to 15% for ACE-ANT-ACE hole transport layer, 27.2% for Spiro-OMeTAD and 32.5% for TPA-ANT-TPA hole transport layers. This clearly shows improved hole extraction as well charge dissociation from perovskite to deposited hole transport layers. The order of effective hole extraction follows a trend: TPA-ANT-TPA > Spiro-OMeTAD > ACE-ANT-ACE.

379 Figure 6 exhibits scanning electron microscope (SEM) images recoded on the 380 perovskite thin film deposited on top of FTO/compact TiO₂/mesoporous TiO₂ substrates, 381 TPA-ANT-TPA and ACE-ANT-ACE on perovskite layer, respectively. Figure 6a clearly 382 shows the perovskite film with a high coverage and a crystal size ranging from 100 to 300 383 nm. Figure 6b, c, and d1 illustrate similar surface thicknesses of TPA-ANT-TPA, Spiro-384 OMeTAD, and ACE-ANT-ACE HTM layers under the same magnification. Among all of the 385 data, Figure 6b obviously shows uniform, defect-free coverage of TPA-ANT-TPA HTM. For 386 Spiro-OMeTAD HTM, weak hydrogen bonding between active CH₃NH₃PbI₃ layer and HTM 387 might be responsible factor for poor morphology than TPA-ANT-TPA. Interface between 388 HTM and CH₃NH₃PbI₃ helps in stabilization of the perovskite phase with a uniform and 389 dense morphology as well as improved crystallites. Such arrangement is responsible for the 390 highly-improved cell performance. Relatively less homogeneous surface is seen for ACE-391 ANT-ACE HTL whereas for Spiro-OMeTAD, the surface is more inhomogeneous with a 392 rough surface morphology (Figure 6d) and at some point, showing crystallization possibly 393 caused by the use of dopants (Figure 6d1). Spin coated Spiro-OMeTAD HTL shows oriented aggregation or crystallization due to its intrinsic features.^[51] Also, spin coated films of ACE-394 395 ANT-ACE and TPA-ANT-TPA films shows small particles which could be attributed with 396 aggregation.

397 These electron microscope observations strongly correlate with the perovskite solar cell 398 stability trends observed in Figure 4. The improved coverage of the TPA-ANT-TPA films 399 resulted in devices with much higher stability whereas the HTM films with small to large pin-400 holes exhibited lower stability. The good coverage of the HTM on the perovskite layer is an 401 extremely important parameter besides its hole transporting ability. It assures protection of the perovskite thin film layer from the exposure to oxygen,^[47] humidity,^[48, 52] and heat.^[52] 402 403 These external exposures are main culprits for the quick degradation of PSCs under ambient 404 conditions. In addition to the surface morphology of HTMs on perovskite layer, we also 405 performed contact angle measurements (Figure S10, ESI⁺) on TPA-ANT-TPA and ACE-406 ANT-ACE deposited thin films on perovskite layer to confirm the hydrophobicity of the 407 surface. The obtained data show a bad wetting behaviour with an elevated angle (85°) of 408 water droplets for TPA-ANT-TPA surface, whereas a good wetting was observed with a 409 lower contact angle (47°) for the Spiro-OMeTAD layer. The higher stability of TPA-ANT-410 TPA based PSCs is due to its higher hydrophobic nature that will protect the perovskite layer 411 underneath. To further investigate the stability of all three HTMs, TPA-ANT-TPA, ACE-412 ANT-ACE and Spiro-OMeTAD are deposited on the perovskite layer and are subjected to 1 413 sun (AM 1.5G) continuous illumination for two weeks.

414 The crystalline and absorbing characteristics of the perovskite covered with the three 415 different HTLs before and after 1 sun illumination for 2 weeks are measured using XRD and 416 UV-visible spectroscopy as shown in Figure S16, ESI[†]. The perovskite covered with TPA-417 ANT-TPA and ACE-ANT-ACE does not show any sign of degradation and perovskite layers 418 underneath continue to show high crystallinity and absorbance after 2 weeks of continuous 1 419 sun illumination (Figure S16(a), (b), (c), (d), ESI[†]). However, the perovskite layer covered 420 with Spiro-OMeTAD shows complete degradation of the perovskite to PbI₂ as observed from 421 Figure S16(c), (f), ESI[†].

422 A comparison of lab cost difference between TPA-ANT-TPA and Spiro-OMeTAD HTMs is given in Table 3. The synthesis cost of TPA-ANT-TPA is estimated by using the 423 price of chemical suppliers in Australia and following previous attempts.^[53, 54] Its further 424 details can be found in Table S2-5 (ESI[†]). The flowchart describing the synthesis of 1g of 425 426 TPA-ANT-TPA was illustrated in Figure S17 (ESI[†]). Meanwhile, the price of synthetic Spiro-OMeTAD's HTM is surveyed from earlier reports and its commercial price is also 427 mentioned.^[53, 55] The cost of our newly developed high performance TPA-ANT-TPA HTM 428 429 (taking both efficiency and stability into an account) is roughly two third that of synthetic 430 Spiro-OMeTAD and it can further drop if large scale synthesis is performed.

A brief comparison among dopant-free HTMs using TPA moiety as either the central 431 432 core or the end-capping groups has been conducted and listed in Table 4. These preferred 433 HTMs have similar device structure: FTO/compactTiO₂/mesoporous 434 TiO₂/CH₃NH₃PbI₃/HTM/cathode with approximately equivalent working area. Their photovoltaic parameters of the solar cells were evaluated under 1 sunlight illumination (100 435 436 mW cm⁻²) condition. Overall, the device with TPA-ANT-TPA as HTM displays the highest FF whereas the V_{oc} and J_{sc} are among the best values in comparison with other ones. This 437 438 material also possesses the impressive hole mobility which may be a trigger to the superior 439 values of the FF and J_{sc} . Even though the TPA-CN and TPA-ANT-TPA based devices exhibited the similar efficiency (17.5%), the performance of TPA-CN was lower than that of 440 the reference device based on Spiro-OMeTAD under similar conditions.^[35] During the ageing 441 442 test without encapsulation at room temperature, the PCE achieved using our TPA-ANT-TPA 443 as HTM maintained 80% of the initial value. Even thought this may be lower than that of 444 Z34, Me-QTPA, EDOT-OMeTPA, and Z1011, their initial performance was worse than that of our material based devices. According to the tabular comparison, our novel TPA-ANT-445 446 TPA HTM can become a suitable and promising alternative to Spiro-OMeTAD.

447 Overall, the better performance and stability properties of PSCs made using TPA-448 ANT-TPA based hole transport layers are due to the following factors: (a) better charge 449 extraction - the experimental photoluminescence spectroscopy shows enhanced quenching for 450 TPA-ANT-TPA based perovskite devices due to better hole transfer. Additionally, it is also a 451 result of close alignment of HOMO energy levels of the HTM and perovskite with minimal 452 band offset; (b) stability improvement - the improved morphology, uniformity and a good 453 surface coverage of the capping layer of TPA-ANT-TPA. The hydrophobic nature of the 454 TPA-ANT-TPA surface as seen from contact angle measurements makes the PSCs made 455 from TPA-ANT-TPA HTM more stable than Spiro-OMeTAD based devices. Moreover, 456 avoiding the use of dopants such as LiTFSI enhances the stability (salts often reacts quickly 457 with moisture).

458 In this work, we have successfully designed and synthesized two new small molecular 459 TPA-ANT-TPA and ACE-ANT-ACE HTMs based on an innovative anthanthrone dye as a 460 core. The syntheses of both materials were conducted via a simple coupling protocol using a common anthanthrone dye as a central core and two different tri-phenylamine and 461 462 acenaphthylene end-capping units. A detailed comparison on optoelectronic properties of 463 TPA-ANT-TPA and ACE-ANT-ACE based PSCs has been performed and it is found that a 464 HOMO energy level of TPA-ANT-TPA is close to the active perovskite energy level for 465 better hole transport with minimal energy offset. Upon evaluating both TPA-ANT-TPA and 466 ACE-ANT-ACE as hole transporting materials in perovskite solar cell devices, the highest 467 power conversion efficiency of 13% and 17.5% has been achieved, respectively. The TPA-468 ANT-TPA HTM not only exhibits high performance showing champion efficiency of 17.5% 469 and average efficiency of 16% with increased reproducibility of PSCs as compared to Spiro-470 OMeTAD based PSCs but also shows a lower cost and straightforward synthesis with easy 471 purification. One of the most important striking features of TPA-ANT-TPA based PSC

472 devices is its environmental stability which is much higher than that with classical Spiro-473 OMeTAD. This is a most critical parameter, and the most discussed aspects in the perovskite 474 solar cell community. The significantly higher stability of the TPA-ANT-TPA based devices 475 is due to the hydrophobic nature and homogeneous coverage as a result of more extended 476 chemical structure of TPA on the perovskite capping layer. The TPA-ANT-TPA HTM 477 without additives resulted in increased V_{oc} and improved moisture resistance of PSCs, as a result of more uniform formation of TPA-ANT-TPA capping layer on the surface of 478 479 perovskite leading to a more efficient hole transport than with Spiro-OMeTAD. The 480 improved charge collection efficiency in devices prepared with TPA-ANT-TPA HTL (as 481 seen from effective PL quenching) compared to that of ACE-ANT-ACE and Spiro-OMeTAD 482 HTL leads to higher short circuit current and photovoltage. In summary, we successfully 483 demonstrated the great potential of a low cost anthanthrone dye as a starting precursor for 484 designing highly efficient HTMs for stable and low cost efficient PSCs. Using such efficient, 485 stable and low cost HTMs, it must be possible to produce the large-scale roll-to-roll printed 486 perovskite solar cell modules and prototypes for commercialization and energy harvesting 487 application.

488 **Experimental Section**

489 Detailed experimental methods can be found in the Supporting Information.

490 Supporting Information

491 Supporting Information is available from the Wiley Online Library or from the author.492

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- 657



Scheme 1. Synthetic approach to ACE-ANT-ACE and TPA-ANT-TPA. Reagent and
conditions: (a) 1-iodo-4-methoxybenzene, KOH, CuCl, 1,10-phenanthroline monohydrate,
toluene, 120 °C, overnight; (b) bis(pinacolato)diboron, KOAc, Pd(dppf)Cl₂, DMF, 120 °C,
overnight; (c) Na₂S₂O₄, C₈H₁₇Br, aliquat 336, NaOH (aq.), 120 °C, overnight; (d) 2M K₂CO₃,
toluene, Pd(PPh₃)₄, 120 °C,48 h.



Figure 1. Chemical structures, geometrical configuration (front view and side view), and
calculated isosurfaces and energy levels of HOMO and LUMO orbital surfaces of (a) ACEANT-ACE and (b) TPA-ANT-TPA.



Figure 2. (a) UV-Vis absorption spectra in CF solutions (dash line) and films (solid line), (b)
Photoelectron spectroscopy in air (PESA) spectra, (c) Energy level diagrams, (d) Crosssectional scanning electron microscopy image of PSC without dopants.



677 Figure 3. Photovoltaic performance with hysteresis of optimized champion PSC devices made using different hole transport layers: (a) Using ACE-ANT-ACE (green curve) TPA-678 679 ANT-TPA (blue curve) as the hole transporting layer and Spiro- OMeTAD (red curve and 680 black curve) as the hole transporting layer; and (b) Absolute EQE spectra (solid line) and 681 integrated current densities (dashed lines) of optimized PSC solar cells prepared using 682 different hole transporting layers as ACE-ANT-ACE (green), TPA-ANT-TPA (blue) and 683 Spiro-OMeTAD (red). (c) Power output under maximum power point tracking for 270 s, 684 starting from forward bias and resulting in a stabilized power output of 17.5%, 16.6% and 685 13% for TPA-ANT-TPA, ACE-ANT-ACE and Spiro-OMeTAD based devices respectively (at 960 mV). The voltage scan rate for all scans was 10 mVs⁻¹ and no device preconditioning, 686 687 such as light soaking or forward voltage bias applied for a long time, was applied before 688 starting the measurement.



Figure 4. Photovoltaic performance of TPA-ANT-TPA (a) and Spiro-OMeTAD (b) based CH₃NH₃PbI₃ PSC devices respectively on aging in humidity \geq 58% (the fresh and aged PSC devices shown in satellite pictures); Stability test/aging for 50 hours: without encapsulation for, TPA-ANT-TPA and Spiro-OMeTAD based CH₃NH₃PbI₃ PSC devices at RH \geq 58%, After each consecutive measurement, the PSCs are kept in an ambient humidity setup of RH \geq 58%, Temperature = 22 °C, in dark condition. Grey colour scale represents humid condition RH \geq 50 %, Temperature = 22 °C, in dark condition.



Figure 5. (a) Steady state Photoluminescence (PL) measured on bare perovskite film (black),
and hole transport layer deposited on the perovskite. Red, green, and blue curves represent
Spiro-OMeTAD, ACE-ANT-ACE, TPA-ANT-TPA, respectively, deposited on perovskite.
(b) Time resolved PL taken at excitation wavelength of 765 nm of the perovskite films with
different hole transport layers. A 5 mW picosecond pulsed diode laser at 635 nm excited on
the perovskite and hole transport layer side.



Figure 6. (a) Surface image of perovskite films deposited on top of FTO/compact
TiO₂/mesoporous TiO₂; (b) Top view of TPA-ANT-TPA on a perovskite layer; (c), and (c1)
top view of ACE-ANT-ACE on a perovskite layer; (d) and (d1) top view of Spiro-OMeTAD
on a perovskite layer.

Table 1. Thermal, optical and electrochemical properties of ACE-ANT-ACE and TPA-ANTTPA

	λ_{\max} [1	nm]	$\lambda_{PL}{}^{c)}$	$E_g^{opt_{\rm d})}$	$E_{\rm HOMO}^{\rm e)}$	$E_{\rm LUMO}^{\rm e)}$	$E_{\rm HOMO}^{\rm f)}$	T_d	T_m
H I MIS	Solution ^{a)}	Film ^{b)}	 [nm]	[eV]	[eV]	[eV]	[eV]	[°C]	[°C]
ACE-ANT-ACE	461	467	480	2.56	-5.32	-2.76	-5.28	265	215
TPA-ANT-TPA	465	473	553	2.48	-5.41	-2.93	-5.40	290	256

^{a)}Absorption spectrum was measured in chloroform (CF) solution; ^b Film was prepared by spincoating an CF solution containing the sample onto glass substrate at a spin speed of 1000 rpm at room temperature; ^cEmission spectrum was analysed in CF solution; ^dOptical bandgap was calculated from the formula of $1240/\lambda_{onset}$; ^eThe oxidation potential was also measured by photoelectron spectroscopy in air (PESA); $E_{LUMO}^{PESA} = E_{HOMO}^{PESA} + E_g^{opt}$; ^f Oxidation potential of the material was characterized in dichloromethane with 0.1 M tetrabutylammonium hexafluorophosphate at scan speed 100 mV/s, potentials vs. Fc/Fc⁺.

Table 2. Summary of champion as well average photovoltaic performance and hole mobility
 of PSC devices prepared with different HTLs as ACE-ANT-ACE, TPA-ANT-TPA and
 Spiro-OMeTAD.^{a)}

						Hole
	Scan	X 7 FX 71	2	FF		mobility
HILS	Direction	v _{oc} [v]	J _{SC} [mA/cm]	[%]	PCE [%]	$[cm^2 V^{-1} s^-]$
						1]
	Forward	1.03	18.7	67.1	13.1	2.4 x 10 ⁻⁵
ACE-ANT-ACE ^{b)}	Reverse	1.03	17.9	65.3	12.7	
	Average ^{d)}	0.99	17.8	65	11.4	
	Forward	1.03	21.07	79.6	17.5	2.6 x 10 ⁻⁴
TPA-ANT-TPA ^{b)}	Reverse	1.03	21.05	79.6	17.5	
	Average ^{d)}	1.00	21.03	76.5	16	
	Forward	1.04	21.09	76.8	16.8	1.5 x 10 ⁻⁴
Spiro-OMeTAD ^{c)}	Reverse	1.04	21.08	76.8	16.8	
	Average ^{d)}	0.98	20.0	70.2	13.8	

^{a)}Cell size (active area): 0.100 cm². Photovoltaic performance at 1000 wm⁻² (AM1.5G) and
 constant scan speed of 0.1 V/s mesoscopic CH₃NH₃PbI₃ devices; ^{b)}without additives; ^{c)}with
 additives: 4-tert-butylpyridine (*t*BP) and Li-bis(trifluoromethanesulfonyl)-imide (LiTFSI);
 ^{d)}An average device efficiency of total 81 devices.

_	Compound	Material cost [\$/g]	Commercial price [\$/g]
	TPA-ANT-TPA	67	-
	Spiro-OMeTAD	91.67 ^[53, 55]	170-475 ^[53, 55]

Table 3. Comparison of lab synthesis costs of TPA-ANT-TPA and Spiro-OMeTAD.

HTM	HOMO [eV]	Hole mobility [10 ⁻⁴ cm ² V ⁻¹ s ⁻¹]	Active area [cm ²]	^e V _{oc} [V]	J _{sc} [mAcm ⁻²]	FF [%]	PCE [%] ^{e)}	Stability test ^{g)}	References
TPA-ANT-TPA ^{b)}	-5.41	2.6	0.1	1.03	21.07	79.6	17.5 (16.8) ^{f)}	80% (14%) ^{h)}	This study
1 ^{b)}	-5.00	6.0	0.16	0.971	19.3	72	13.4 (15)	-	[45]
Z34 ^{b)}	-5.14	7.46	0.16	1.053	21.27	69	15.9 (16.7)	100% (85%)	[33]
TPB-2-MOTPA ^b	-5.28	0.77	-	0.927	17.37	69	11.06 (13.28)	99% (92%)	[56]
MeO-BPZTPA ^{b)}	-5.29	4.80	0.1	0.917	16.89	66.9	10.36 (13.65)	-	[57]
TAE-1 ^{b)}	-5.32	0.592	-	0.885	17.22	72.2	11.02% (13.53%)	-	[58]
H101 ^{b)}	-5.09	-	0.2	0.99	20.11	59	11.03% (13.7%)	-	[40]
EDOT- OMeTPA ^{b)}	-5.28	-	0.0831	10.95	18.9	61	11% (11.9%)	90% (90%)	[53]
OMeTPA-FA ^{b)}	-5.14	3.67	0.16	0.905	19.42	63	11.07% (14.68%)	88% (89%)	[59]
HTM2 ^{b)}	-5.23	12.7	0.08	0.921	18.1	68	11.63% (12.08%)	-	[60]
2TPA-2-DP ^{c)}	-4.96	1.09	0.08	0.974	18.8	70.7	12.96% (11.46%)	-	[61]
Me-QTPA ^{c)}	-5.25	-	0.1	0.917	14.58	67.8	9.07% (13.65%)	100% (38%)	[62]
apv-EC ^{c)}	-5.28	7.23	0.08	0.932	18.4	70	12.0% (13.1%)	-	[63]
ST1 ^{d)}	-5.24	4.57	0.16	1.059	21.07	66	15.4 (16.3)	85% (63%)	[64]
TPA-CN ^{d)}	-5.38	1.1	0.16	1.09	20.85	77	17.5 (19.2)	-	[35]
TP1 ^{d)}	-5.18	0.441	0.16	0.956	20.23	63	12.63 (14.93)	70% (52%)	[65]
TBPC ^{d)}	-5.33	4.04	0.08	0.942	19.32	72	13.10% (13.28%)	-	[66]
Z1011 ^{d)}	-5.21	8.49	0.16	1.096	20.52	70	16.3 (16.5)	97% (30%)	[32]
Z1013 ^{d)}	-5.14	6.67	0.16	1.027	21.33	70.2	15.4 (16.7)	- (60%)	[34]

Table 4. The comparison of small molecular triphenylamine derivatives based dopant-free
 HTMs^{a)}

^{a)}Device structure: FTO/compact TiO₂/mesoporous TiO₂/CH₃NH₃PbI₃/HTM/Cathode; photovoltaic parameters of the solar cells with HTMs evaluated under 1 sunlight illumination (100 mW cm⁻²) condition.

738 ^{b)}TPA with OMe used as end-capping groups

739 ^{c)}TPA without OMe used as end-capping groups

740 ^{d)}TPA used as the central core

741 ^{e)}The best PCE of the HTMs based devices

742 ^{f)}The best PCE of standard doped SPIRO-OMeTAD

743 ^{g)}The percentage of the retaining performance after the ageing test (unsealed devices, at room temperature)

744 ^{h)}The percentage of the retaining performance of standard SPIRO-OMeTAD

746 **Table of Content Figure**

First time a low cost anthanthrone dye based hole transporting materials ACE-ANT-ACE and TPA-ANT-TPA end capped with dihydroacenaphthylene and triphenyleamine groups were designed and synthesized respectively. Among both, dopant-free TPA-ANT-TPA cutrate HTM (\$67/g) exhibits higher performance with 17.5% efficiency and retains respectable performance after 50 hours in 58% relative humidity than conventional expensive SPIRO-OMeTAD.

753



754

756	Supporting Information
757	Molecular Engineering Using an Anthanthrone Dye for Low
758	Cost Hole Transport Materials: A Strategy for Dopant Free,
759	High Efficiency Perovskite Solar Cells
760	
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780	Figure S1. ¹ H (600 MHz, CDCl ₃) spectrum of 4-bromo- <i>N</i> , <i>N</i> -bis(4-methoxyphenyl)aniline
781	(2)
782	Figure S2. ¹ H (600 MHz, CDCl ₃) spectrum of 4-methoxy- <i>N</i> -(4-methoxyphenyl)- <i>N</i> -(4-
783	(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (3)
784	Figure S3. ¹ H (400 MHz, CDCl ₃) spectrum of 4,10-dibromo-6,12-bis(octyloxy)-6,12-
785	dihydronaphtho[7,8,1,2,3- <i>nopqr</i>]tetraphene (5)
786	Figure S4. (a) 1 H (400 MHz, CDCl ₃) spectrum and (b) 13 C NMR (100 MHz, CDCl ₃)
787	spectrum of ACE-ANT-ACE
788	Figure S5. (a) 1 H (400 MHz, CDCl ₃) spectrum and (b) 13 C NMR (100 MHz, CDCl ₃)
789	spectrum of TPA-ANT-TPA54
790	Figure S6. Normalised absorption and emission spectra of ACE-ANT-ACE and TPA-ANT-
791	TPA in CF solution55
792	Figure S7. Thermogravimetric analysis (TGA) curve of (a) ACE-ANT-ACE and (b) TPA-
793	ANT-TPA55
794	Figure S8. Differential scanning calorimetry (DSC) of (a) ACE-ANT-ACE and (b) TPA-
795	ANT-TPA with scan rate of 10 °C/min under N ₂ atmosphere
796	Figure S9. Cyclic voltammograms of (a) ACE-ANT-ACE and (b) TPA-ANT-TPA. The
797	oxidation was measured in DCM/0.1M Bu_4NPF_6 at a scan rate of 100 mV/s56
798	Figure S10. Contact angle measurements performed on Spiro-OMeTAD and TPA-ANT-TPA
799	surface deposited on CH ₃ NH ₃ PbI ₃ 57

779

Content

800	Figure S11. Statistics of 90 PSC devices prepared using (i) ACE-ANT-ACE (green bars); (ii)
801	TPA-ANT-TPA (blue bars) and (iii) Spiro-OMeTAD (red bars) as hole transporting
802	materials
803	Figure S12. (a) FTO/Compact-TiO ₂ /Mesoporous TiO ₂ /CH ₃ NH ₃ PbI ₃ assemblies after
804	annealing; (b) Perovskite devices with 3 different hole transport layers; (c) and (d) Simple
805	stability measurement setup in a humidified desiccator for aging of PSCs in the dark and in
806	>50% humidity
807	Figure S13. Hysteresis behaviour of champion solar cells made using TPA-ANT-TPA (blue
808	curve), ANT-ACE-ANT (green curve) and Spiro-OMeTAD (red curve) as HTLs. Scan from
809	0 V to V_{oc} at a constant scan speed of 0.1 V/s. Device performance parameters represented in
810	the insert table
811	Figure S14. J-V data for space charge limited current (SCLC) method of hole-mobility
812	determination. The resulting mobilities of TPA-ANT-TPA (blue line), ACE-ANT-ACE
813	(green line) and Spiro-OMeTAD (red line) were 2.6 x 10^{-4} , 2.4 x 10^{-5} , 1.5 x 10^{-4} cm ² V ⁻¹ s ⁻¹
814	respectively
815	Figure S15. Stability measurements of champion devices under continuous 1 sun, AM 1.5 G
816	illuminations and at short circuit conditions. comparison of the aging of (a) PCE, (b) Fill
817	factor, (c) Current and (d) open circuit voltage of devices prepared using HTMs, TAP-ANT-
818	TPA (blue line), ACE-ANT-ACE (green line) and Spiro-OMeTAD (red line)60
819	Figure S16. (a),(b),(c) XRD and (d), (e), (f) UV-visible degradation study of all three
820	respective HTMs deposited on glass / perovskite assembly. All samples kept under
821	continuous 1 sun illumination, in ambient air and at ~35°C (sample temperature measured
822	during illumination)61
823	Figure S17. Flowchart describing the synthesis of 1g of TPA-ANT-TPA62

824	
825	Table S1. Density Functional Theory (DFT) calculations of ACE-ANT-ACE and TPA-ANT-
826	TPA63
827	Table S2. Materials quantities and cost evaluation for the synthesis of 4-bromo-N,N-bis(4-
828	methoxyphenyl)aniline (2)
829	Table S3. Materials quantities and cost evaluation for the synthesis of 4-methoxy-N-(4-
830	methoxyphenyl)- <i>N</i> -(4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (3)65
831	Table S4. Materials quantities and cost evaluation for the synthesis of 4,10-dibromo-6,12-
832	bis(octyloxy)anthanthrene (5)
833	Table S5. Materials quantities and cost evaluation for the synthesis of 4,4'-(6,12-
834	bis(octyloxy)-6,12-dihydronaphtho[7,8,1,2,3- <i>nopqr</i>]tetraphene-4,10-diyl)bis(N,N-bis(4-
835	methoxyphenyl)aniline) (TPA-ANT-TPA)

837 **Experimental details**

838

839 1. Materials and Instruments

840 All chemicals and reagents were purchased from commercial company and used directly without any further purification. Synthesized compounds were characterized by ¹H-NMR and 841 ¹³C-NMR spectrum, which were obtained with a Varian-400 spectrometer or a Bruker 600 842 843 MHz spectrometer. High-resolution mass spectra were acquired on an LTQ Orbitrap Elite 844 mass spectrometer (Thermo Fisher Scientific, Bremen, Germany) equipped with an 845 electrospray ionisation (ESI) source, operating in the positive ion mode at a resolution of 846 120,000 (at m/z 400). Reserving ([M+H]⁺, m/z 609.28066) was used as a lock mass calibrant 847 to increase the measurement accuracy. Thermal analysis was performed using a Pegasus 848 Q500TGA thermogravimetric analyzer under nitrogen atmosphere at a heating rate of 10 849 ^oC/min. Differential scanning calorimetry (DSC) was conducted under nitrogen using a Chimaera instrument Q100 DSC. The sample was heated at 10 °C/min from 30 °C to 300 °C. 850 851 Absorption spectra were recorded on a Shimadzu UV-1800 spectrometer. Photoelectron 852 spectroscopy in air (PESA) measurements were conducted using on an AC-2 photoelectron spectrometer (Riken-Keiki Co.). The cyclic voltammetry (CV) was performed by a 853 854 Potentiostat Galvanostat with a three electrode cell in a solution of Bu₄NPF₆ (0.1M) in freshly distilled DCM at a scan rate of 100 mV/s. The counter electrode was a Pt wire, the 855 working electrode was glassy carbon and an Ag/Ag+ electrode was used as the reference 856 857 electrode.

858

859 **2.** Synthesis

860 <u>Synthesis of 4-bromo-*N*,*N*-bis(4-methoxyphenyl)aniline (2)</u>

Compound 1 (2 g, 11.6 mmol), 1-iodo-4-methoxybenzene (5.97 g, 25.5 mmol.), KOH (5.1 g, 861 862 90.5 mmol), CuCl (0.05 g, 0.5 mmol) and 1,10-phenanthroline monohydrate (0.1 g, 0.5 863 mmol) were dissolved in anhydrous toluene. After being degassed by argon for 20 min, the 864 reaction mixture was heated at 120 °C overnight. Then the mixture was cooled to room 865 temperature (RT). Excessive potassium hydroxide (KOH) was neutralized by water. After 866 that, the mixture was extracted by dichloromethane (DCM). The organic layer was dried over anhydrous sodium sulphate (Na₂SO₄) and concentrated by evaporation. The crude product 867 868 was purified by silica gel chromatography using a mixture of hexane and DCM as eluent to obtain product as a white crystal (2.5 g, 56%). ¹H NMR (600 MHz, CDCl₃, ppm): δ 7.16 (d, J 869 870 = 9.0 Hz, 2H), 6.95 (d, J = 8.4 Hz, 4H), 6.75 (d, J = 8.4 Hz, 4H), 6.72 (d, J = 8.4 Hz, 2H), 871 3.72 (s, 6H).

872 <u>Synthesis of 4-methoxy-N-(4-methoxyphenyl)-N-(4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-</u> 873 <u>2-yl)phenyl)aniline (3)</u>

874 In a Schlenk flask, compound 2 (2.5 g, 6.5 mmol) was mixed with diborane pinacol ester (2.5 875 g, 9.8 mmol), KOAc (1.9 g, 19.6 mmol) and Pd(dppf)Cl₂ (1.2 g, 1.6 mmol) in 50 mL 876 dimethylformamide (DMF). Then, the mixture was heated overnight at 80 °C. After cooling 877 to RT, the reaction mixture was extracted by chloroform (CF) and water. Subsequently, it was dried over anhydrous Na₂SO₄ and then concentrated by evaporation. The residue was 878 879 purified by silica gel chromatography using a mixture of hexane and DCM as eluent to obtain product as a white crystal (1.8 g, 64%). ¹H NMR (600 MHz, CDCl₃, ppm): δ 7.53 (d, J = 7.2 880 881 Hz, 2H), 6.98 (m, 4H), 6.78-6.74 (m, 6H), 3.72 (s, 6H), 1.24 (s, 12H).

- 882 Synthesis of 4,10-dibromo-6,12-bis(octyloxy)anthanthrene (5)
- 883 Compound 4 (2.0 g, 4.3 mmol), aqueous sodium hydroxide (0.2 M, 20 mmol), Aliquat 336
- 884 (2.1 g, 5.2 mmol), sodium dithionite (1.9 mg, 11.1 mmol), and 1-bromooctane (6.6 g, 34.3

mmol) were added into a round bottom flask and then degassed by argon for 20 min. The mixture was stirred at 80 °C overnight. The crude component was extracted by water and methanol. The organic layer was dried over anhydrous Na₂SO₄ and concentrated by evaporation. Purification by using column chromatography yielded the main product as an orange solid (2.4 g, 80%). ¹H NMR (400 MHz, CDCl₃, ppm): δ 8.78-8.75 (m, 4H), 8.63 (d, *J* = 7.6 Hz, 2H), 8.22-8.18 (t, *J* = 8.0 Hz, 2H), 4.34-4.31 (t, *J* = 6.4 Hz, 4H), 2.15 (m, 4H), 1.76 (m, 4H), 1.37-1.24 (m, 16H), 0.94-0.91 (t, *J* = 6.8 Hz, 6H).

892 Synthesis of 2-(1,2-dihydroacenaphthylen-5-yl)-4,4,5,5-tetramethyl-1,3,2-dioxaborolane (6) :

Into a Schlenk flask, commercially available 5-bromo-1,2-dihydroacenaphthylene (2.89 g, 893 894 12.4 mmol) was mixed with diborane pinacol ester (3.29 g, 13 mmol), KOAc (3.31 g, 33.6 895 mmol) and Pd(dppf)Cl₂ (271 mg) in 80 mL dioxane. Then, the mixture was heated overnight 896 at 80°C. After cooling to RT, the reaction mixture was extracted by chloroform (CF) and 897 water. Subsequently, it was dried over anhydrous magnesium sulphate and then concentrated 898 by evaporation. The residue was purified by silica gel chromatography using a mixture of 899 hexane and ethyl acetate as eluent to obtain product 2-(1,2-dihydroacenaphthylen-5-yl)-900 4,4,5,5-tetramethyl-1,3,2-dioxaborolane (6) as a white powder (1.8 g, 51%). 1H NMR (400 901 MHz, CDCl3, ppm): $\delta 8.36$ (d, J = 8.4 Hz, 1H), 8.04-8.02 (d, J = 6.8 Hz, 1H), 7.50-7.47 (m, 1H), 7.29-7.27 (d, J = 7.2 Hz, 2H), 3.38 (s, 4H), 1.40 (s, 12H). 902

903 Synthesis of 4,10-bis(1,2-dihydroacenaphthylen-5-yl)-6,12-bis(octyloxy)-6,12 904 <u>dihydronaphtho[7,8,1,2,3-nopqr]</u> tetraphene (ACE-ANT-ACE)

905 In a round bottom flask, compound 5 (200 mg, 0.290 mmol), compound 6 (245 mg, 0.875 906 mmol), and 2M aqueous K₂CO₃ solution (12 mL) were dissolved in degassed toluene (18 907 mL). The solution was purged with argon for 15 minutes, then 908 tetrakis(triphenylphosphine)palladium (16.18 mg 0.014 mmol) was added. The reaction was

909 stirred at 120 °C for 2 days. After the reaction mixture was cooled to room temperature and 910 extracted with chloroform and water. The organic layer was dried over anhydrous Na₂SO₄ 911 and concentrated by evaporation. The solvent was evaporated and the crude product 912 recrystallized from hot acetone to yield the desired compound as a yellow solid (205 mg, 65%). ¹H NMR (400 MHz, CDCl₃, ppm): δ 8.81 (d, *J* = 8.0 Hz, 2H), 8.57 (s, 2H), 8.01-7.98 913 914 (t, J = 8.0 Hz, 2H), 7.92 (d, J = 7.2 Hz, 2H), 7.79 (d, J = 6.8 Hz, 2H), 7.55-7.54 (d, J = 7.2 Hz, 2H)915 Hz, 2H), 7.44-7.42 (m, 2H), 7.37-7.31 (m, 4H), 4.42-4.38 (t, J = 6.8 Hz, 4H), 3.58 (m, 8H), 2.08 (m, 4H), 1.63 (m, 4H), 1.26 (m, 16H), 0.88-0.84 (t, J = 6.8 Hz, 6H). ¹³C NMR (CDCl₃, 916 917 ppm): δ 149.55, 146.20, 146.12, 139.47, 137.96, 134.18, 132.25, 131.40, 129.74, 129.68, 918 127.95, 125.93, 125.71, 124.38, 123.68, 123.90, 121.90, 121.66, 120.47, 120.05, 119.48, 919 119.31, 119.24, 31.79, 30.71, 30.31, 29.52, 29.28, 26.19, 22.65, 14.10. ESI-MS: C₆₂H₆₀O₂^{+•} 920 m/z 836.4587 (calculated *m/z* 836.4588).

921 <u>Synthesis of 4,4'-(6,12-bis(octyloxy)-6,12-dihydronaphtho[7,8,1,2,3-*nopqr*]tetraphene-4,10 922 <u>diyl)bis(N,N-bis(4-methoxyphenyl)aniline)</u> (**TPA-ANT-TPA**) </u>

923 In a round bottom flask, compound 5 (200 mg, 0.290 mmol), compound 3 (313 mg, 0.725 924 mmol), and 2M aqueous K₂CO₃ solution (12 mL) were dissolved in degassed toluene (18 925 The mL). solution was purged with argon for 15 minutes, then 926 tetrakis(triphenylphosphine)palladium (16.18 mg 0.014 mmol) was added. The reaction was 927 stirred at 120 °C for 2 days. After the reaction mixture was cooled to room temperature and 928 extracted with chloroform and water. The organic layer was dried over anhydrous Na₂SO₄ 929 and concentrated by evaporation. The solvent was evaporated and the crude product 930 recrystallized from hot acetone to yield the desired compound as a yellow solid (200 mg, 60%). ¹H NMR (400 MHz, CDCl₃, ppm): δ 8.81 (d, J = 8.0 Hz, 2H), 8.41 (s, 2H), 8.38 (d, J931 932 = 7.2 Hz, 2H), 8.14-8.10 (t, J = 8.0 Hz, 2H), 7.60 (d, J = 8.8 Hz, 4H), 7.25-7.21 (m, 8H), 7.15 933 (d, J = 8.4 Hz, 4H), 6.92 (m, 8H), 4.40-4.37 (t, J = 6.8 Hz, 4H), 3.83 (s, 12H), 2.14 (m, 4H),

934 1.72 (m, 4H), 1.31 (m, 16H), 0.90-0.87 (t, J = 6.4 Hz, 6H). ¹³C NMR (100 MHz, CDCl₃, 935 ppm): δ 155.97, 148.27, 140.87, 139.72, 132.72, 131.54, 130.65, 126.91, 126.00, 125.96, 936 125.59, 124.38, 123.11, 122.19, 121.89, 120.40, 119.85, 119.73, 114.76, 55.51, 31.87, 30.80, 937 29.71, 29.61, 29.36, 26.35, 22.69, 14.16. ESI-MS: C₇₈H₇₈N₂O₆^{+•} m/z 1138.5857 (calculated 938 m/z 1138.5854).

939

3. Substrates Preparation: A patterned FTO-coated glass (13 Ω sq⁻¹, Aldrich) was etched by 940 941 Zn powder and 2 M HCl diluted in deionized water. Subsequently, the substrates were 942 cleaned with detergent diluted in deionized water, rinsed with deionized water, acetone and 943 ethanol, and dried with clean dry air. A compact blocking layer of TiO₂ (40 nm, c-TiO₂) was 944 deposited on the fluorine doped SnO₂ (FTO, Pilkington, TEC8) substrate by spray pyrolysis 945 using a 20 mM titanium di-isopropoxide bis(acetylacetonate) solution (Aldrich) at 500°C for 946 947 30 NR-D paste is dissolved in anhydrous isopropanol and kept for sonication for 1 hours. 948 Once the solution is homogeneous it is ready to deposit on FTO/Compact TiO₂ substrate by spin coating at 3000 rpm for 30 second followed by annealing at 550^o C estimated to give 949 ~400 nm thick layer.^[2] 950

951 4. Fabrication of Devices: The PSCs were prepared by one step spin coating of a $CH_3NH_3PbI_3$ solution. The solution was prepared in DMF/DMSO = 6:4 by mixing CH_3NH_3I 952 (0.199 gm) and PbI₂ (0.600 gm). The solution was heated at 60 °C for 3 hours for mixing. 953 954 Then the solution was spin coated using Chlorobenzene as antisolvent at rpm of 4000 for 30 s, and annealed for 30 minutes at 100 °C on a hotplate. The absorber perovskite material with 955 electrode (FTO/Compact-TiO₂/Mesoporous TiO₂) is ready after the above annealing 956 957 procedure. The electrodes with the absorber material were allowed to cool down to room temperature. A solution containing 2-7,7-tetrakis(N,N-di-p-methoxyphenylamine)-9,9 17-958

spirobifluorene (Spiro-OMe-TAD) in chlorobenzene and additives ($10 \ \mu l \ ml^{-1} tBP$, $32 \ \mu l \ ml^{-1}$ Li-TFSI solution: 600 Mm in acetonitrile) was spin coated onto the perovskite film at 5000 rpm, for 30 second. Finally, 80 nm thick silver contacts were evaporated at 10^{-4} torr.

Similarly, other hole transporting materials, TPA-ANT-TPA and ACE-ANT-ACE were dissolved in 60 mg in 1 ml chlorobenzene and kept for sonication for 30 minutes. The solution was filtered (0.45 u) before use and spin coated on top of perovskite absorber at 5000 rpm for 30 seconds.

5. Power Conversion Efficiency and Incident Photon to Current Conversion Efficiency (IPCE): Masked devices (0.100 cm^2) were tested under a class AAA solar simulator (Newport Oriel Sol3A) at AM1.5 and 100 mW cm⁻² illumination conditions calibrated against a KG5 filtered silicon reference cell (Newport Oriel 91150-KG5) using a Keithley 2400 source meter. Current–voltage sweeps were performed from forward-to-reverse bias at a rate of 0.1 V s⁻¹.

6. Stability Measurements: Humidity test : Stability tests on optimized champion devices
without encapsulation for different hole transporting material were performed. The solar cells
were kept in relative humidity of >580% at room temperature in the dark. The simple setup is
shown in Figure S12.

Continuous 1 sun illumination: The non-encapsulated cells are placed in a cell holder with a glass cover and are in direct contact with ambient atmosphere. For the stability the cells are kept at 35° C temperature, under 1sun illumination using Solar simulator class A 1.5 M at full sun under short circuit condition for 200 hours. IV curves were characterized by an electronic system using 22 bits delta-sigma analogic to digital converter. For IV curves measurement, a scan rate of 10 mV s⁻¹ with a step of 5 mV was used, maintaining the temperature of the holder to 35° C while the temperature of the cells was measured around 45° C. The system

comprises a set of I–V curves at different light intensities (dark current, 10 and 100 mW cm⁻
²). Between each measurement the cells are maintained at the maximum power point using a
MPPT algorithm under 100 mW cm⁻². A reference Si-photodiode is placed in the holder to
verify the stability of the light. The same setup was used to do the aging of all three HTLs,
which are covered on perovskite material (Figure S15).

988 **7. Characterisation**:

989 Scanning Electron Microscopy (SEM): high magnification observations of the hole 990 transport materials and device cross sections were acquired using a Hitachi S-4800 field 991 emission gun-scanning electron microscope (5 kV, WD-8 mm)

992 Photoluminiscence Measurements: Steady state emission measurements were done on the 993 Horiba Fluoromax-4 spectroflurometer equipped with double-grating at the excitation 994 wavelength of 550 nm on the 3-layer assembly Glass/CH₃NH₃PbI₃/HTM with different 995 HTMs (TPA-ANT-TPA, ACE-ANT-ACE, and Spiro-OMeTAD). Front face illumination 996 with respect to the incident beam was used to minimize the inner filter effects.

997 **Contact Angle Measurements:** Contact angle measurements were performed using a 998 simple home built instrument. High resolution images of water droplets on the surface of hole 999 transport layers deposited on the perovskite sample were collected using Nikon DSL90 1000 camera, as shown in Figure S11.

1001 **Time Correlated Single Photon Counting (TCSPC):** Time Correlated Single Photon 1002 Counting measurements were performed on Horiba Jobin Yvon Fluorolog system. Steady 1003 state photoluminiscence measurements were done on perovskite and hole transport layers 1004 with < 200 ps pulses of 635 nm excitation from a pisosecond diode laser (NanoLED source). 1005 The laser pulse excitation density was 2.3×10^{14} cm⁻³, Rep.rate:1MHz. Measurements were 1006 done in reverse mode at 1 MHz rep. rate. A cutoff filter (OG575) was used to block the stray

1007 excitation light. To increase the sensitivity of measurements, all wavelengths transmitted by

1008 cutoff filter were collected without the use of any monochromator.

1009 Hole transport measurements : space charge limited current (SCLC) method

1010 PEDOT: PSS (Poly(3,4-ethylendioxythiophene)-poly (styrene sulfonate)) was spin-coated 1011 onto indium tin oxide substrate (ITO) and dried at 130 °C for 20 minutes in vacuum. The 1012 purpose of PEDOT: PSS layer (40 nm) was to reduce the roughness of ITO as well as to 1013 improve the work function, achieving enhanced hole-only device properties. The HTMs were 1014 spincoated onto PEDOT: PSS from chloroform solution (30 mg/mL) in a nitrogen 1015 atmosphere. Finally, Au contacts (400 nm thick) were applied via thermal evaporation through a shadow mask in 2 x 10^{-6} Torr vacuum. The work function of Au and ITO are close 1016 1017 to the HOMO energy level of the HTM as well as far below the LUMO energy level. 1018 Therefore, the electron injection barrier is higher than the corresponding hole injection barrier. As a result, the transport is dominated by holes. The J–V characteristics of the sample 1019 1020 was measured with a Keithley 2420 source meter unit at room temperature. The device configuration and equations to extract mobility has been reported by us previously.^[3] 1021



Figure S1. ¹H (600 MHz, CDCl₃) spectrum of 4-bromo-*N*, *N*-bis(4-methoxyphenyl)aniline 1025 (2).



Figure S2. ¹H (600 MHz, CDCl₃) spectrum of 4-methoxy-N-(4-methoxyphenyl)-N-(4-1028 (4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (3).



Figure S3. ¹H (400 MHz, CDCl₃) spectrum of 4,10-dibromo-6,12-bis(octyloxy)-6,12-1031 dihydronaphtho[7,8,1,2,3-*nopqr*]tetraphene (5).



Figure S4. (a) 1 H (400 MHz, CDCl₃) spectrum and (b) 13 C NMR (100 MHz, CDCl₃) 1035 1036 spectrum of ACE-ANT-ACE.



Figure S5. (a) ¹H (400 MHz, CDCl₃) spectrum and (b) ¹³C NMR (100 MHz, CDCl₃) 1040 spectrum of TPA-ANT-TPA.



Figure S6. Normalised absorption and emission spectra of ACE-ANT-ACE and TPA-ANT-TPA in CF solution.





Figure S7. Thermogravimetric analysis (TGA) curve of (a) ACE-ANT-ACE and (b) TPA-ANT-TPA.



Figure S8. Differential scanning calorimetry (DSC) of (a) ACE-ANT-ACE and (b) TPA-1055 ANT-TPA with scan rate of 10 °C/min under N_2 atmosphere.







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1064 Figure S10. Contact angle measurements performed on Spiro-OMeTAD and TPA-ANT-TPA

1065 surface deposited on CH₃NH₃PbI₃.





1066

Figure S11. SEM cross sectional image of perovskite device with thin film morphology
 comparison of both HTM (upper) and statistics of 90 PSC devices prepared using (i) ACE ANT-ACE (green bars); (ii) TPA-ANT-TPA (blue bars) and (iii) Spiro-OMeTAD (red bars)
 as hole transporting materials (lower)



1075Figure S12. (a) FTO/Compact-TiO2/Mesoporous $TiO_2/CH_3NH_3PbI_3$ assemblies after1076annealing; (b) Perovskite devices with 3 different hole transport layers; (c) and (d) Simple1077stability measurement setup in a humidified desiccator for aging of PSCs in the dark and in1078>50% humidity.



1081Figure S13. Hysteresis behaviour of champion solar cells made using TPA-ANT-TPA (blue1082curve) , ANT-ACE-ANT (green curve) and Spiro-OMeTAD (red curve) as HTLs. Scan from10830 V to V_{oc} at a constant scan speed of 0.1 V/s. Device performance parameters represented in1084the insert table.

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Figure S14. J-V data for space charge limited current (SCLC) method of hole-mobility determination. The resulting mobilities of TPA-ANT-TPA (blue line), ACE-ANT-ACE (green line) and Spiro-OMeTAD (red line) were 2.6 x 10^{-4} , 2.4 x 10^{-5} , 1.5 x 10^{-4} cm²V⁻¹s⁻¹ respectively.



Figure S15. Stability measurements of champion devices under continuous 1 sun, AM 1.5 G
illuminations and at short circuit conditions. comparison of the aging of (a) PCE, (b) Fill
factor, (c) Current and (d) open circuit voltage of devices prepared using HTMs, TAP-ANTTPA (blue line), ACE-ANT-ACE (green line) and Spiro-OMeTAD (red line).





1103 1104

Figure S16. (a),(b),(c) XRD and (d), (e), (f) UV-visible degradation study of all three respective HTMs deposited on glass / perovskite assembly. All samples kept under continuous 1 sun illumination, in ambient air and at $\sim 35^{\circ}$ C (sample temperature measured during illumination).



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1112 ^aTotal estimated weight of chemical waste, including solvents and precipitate, for the synthesis of 1 gram of 1113 product.

^bTotal estimated weight of halogenated solvents (such as CF and DCM) is given in parentheses for the synthesis of 1 gram of product.

1116 ^cThe density of solvents (Toluene, DMF, DCM, CF, Hexane, Acetone) are referenced from Sigma-Aldrich 1117 supplier.

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- 1119

Figure S17. Flowchart describing the synthesis of 1g of TPA-ANT-TPA.

1120 1121 Table S1. Density Functional Theory (DFT) calculations of ACE-ANT-ACE and TPA-ANT-

TPA.

Compound	ACE-ANT-ACE	TPA-ANT-TPA
HOMO, eV	-4.80	-4.67
LUMO, eV	-2.06	-2.04
gap, eV	2.75	2.63
VIS peak(s), nm	476	524, 467
osc strength	0.4569	0.228, 0.3535
composition	H->L 100%	H->L 85%, H-2->L 83%
PL peak(s), nm	542	633, 571, 512
osc strength	0.5789	0.0812, 0.1212, 0.5186
composition	H->L 100%	H->L 100%, H-1->L 86%, H-2->L 85%
dipole moment, D	0.16	0.17
dihedrals (counted from centre. TPA not counted)		
1	67, 71	51, 53
2	n/a	n/a

1122

Table S2. Materials quantities and cost evaluation for the synthesis of 4-bromo-*N*,*N*-bis(4-

1125 methoxyphenyl)aniline (**2**)



Chemical Name	Weight reagent [g]	Weight solvent [mL]	Weight of workup [g or mL]	Price of chemical [AUD/g or AUD/mL]	Material Cost [AUD/g product]	Cost per step [AUD/step]
4-bromoaniline	1.76			0.32	0.57	31.91
1-iodo-4- methoxybenzene	5.26			0.65	3.40	
КОН	4.47			0.02	0.10	
CuCl	0.04			3.27	0.14	
1,10- phenanthroline monohydrate	0.09			0.78	0.07	
anhydrous Toluene		30.00		0.07	2.15	
DCM		550.00		0.01	3.41	
Na ₂ SO ₄			2.2	0.02	0.05	
SiO ₂			579	0.03	16.30	
Hexane			700	0.01	4.49	
DCM			200	0.01	1.24	

- **Table S3.** Materials quantities and cost evaluation for the synthesis of 4-methoxy-*N*-(4-
- 1131 methoxyphenyl)-*N*-(4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (**3**)



Chemical Name	Weight reagent [g]	Weight solvent [mL]	Weight of workup [g or mL]	Price of chemical [AUD/g or AUD/mL]	Material Cost [AUD/g product]	Cost per step [AUD/step]
diborane pinacol ester	2.18			0.65	1.41	28.38
KOAc	1.69			0.22	0.37	
Pd(dppf)Cl ₂	0.13			32.40	4.07	
DMF		25.00		0.15	3.78	
CF		400.00		0.01	2.96	
Na ₂ SO ₄			1.58	0.02	0.03	
SiO2			415	0.03	11.69	
Hexane			520	0.01	3.34	
DCM			120	0.01	0.74	

Table S4. Materials quantities and cost evaluation for the synthesis of 4,10-dibromo-6,12-

1136 bis(octyloxy)anthanthrene (**5**)



Chemical Name	Weight reagent [g]	Weight solvent [mL]	Weight of workup [g or mL]	Price of chemical [AUD/g or AUD/mL]	Material Cost [AUD/g product]	Cost per step [AUD/step]
4,10-dibromo anthanthrone	0.85			0.21	0.18	14.51
NaOH	0.34			0.02	0.01	
Aliquat 336	0.89			0.50	0.51	
sodium dithionite	0.82			0.10	0.08	
1-bromooctane	2.82			0.25	0.70	
CF		250.00		0.01	1.85	
Na ₂ SO ₄			1	0.02	0.02	
SiO ₂			263	0.03	7.41	
Hexane			200	0.01	1.28	
DCM			400	0.01	2.48	

1140 Table S5. Materials quantities and cost evaluation for the synthesis of 4,4'-(6,12-

1141 bis(octyloxy)-6,12-dihydronaphtho[7,8,1,2,3-*nopqr*

]tetraphene-4,10-diyl)bis(N,N-bis(4-

1142 methoxyphenyl)aniline) (**TPA-ANT-TPA**)



1143

Chemical Name	Weight reagent [g]	Weight solvent [mL]	Weight of workup [g or mL]	Price of chemical [AUD/g or AUD/mL]	Material Cost [AUD/g product]	Cost per step [AUD/step]
K ₂ CO ₃	16.60			0.17	2.84	11.09
tetrakis(triphenylphos phine)palladium	0.05			24.00	1.20	
Toluene		60.00		0.07	4.29	
CF		250.00		0.01	1.85	
Na ₂ SO ₄			1	0.02	0.02	
Acetone			150	0.01	0.89	

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